



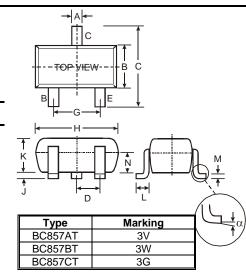
PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

#### **Features**

- Epitaxial Die Construction
- Complementary NPN Types Available (BC847AT,BT,CT)
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability
- "Green" Device (Note 4 and 5)

## Mechanical Data

- Case: SOT-523
- Case Material Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking Code: See Table Below & Diagram on Page 2
- Ordering & Date Code Information: See Page 2
- Weight: 0.002 grams (approximate)



SOT-523								
Dim	Min	Max	Тур					
Α	0.15	0.30	0.22					
В	0.75	0.85	0.80					
С	2 0110 0100 010							
D			0.50					
G	0.90	1.10	1.00					
Н	1.50	1.70	1.60					
J	0.00	0.10	0.05					
К	0.75							
L	0.10	0.30	0.22					
М	0.10	0.20	0.12					
Ν	0.45 0.65		0.50					
α	0°	8°						
aii d	imens	ions in	mm					

#### Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit		
Collector-Base Voltage		V <sub>CBO</sub>	-50	V		
Collector-Emitter Voltage		V <sub>CEO</sub>	-45	V		
Emitter-Base Voltage		V <sub>EBO</sub>	-5.0	V		
Collector Current		lc	-100	mA		
Power Dissipation	(Note 1)	Pd	150	mW		
Thermal Resistance, Junction to Ambient	(Note 1)	$R_{ ext{ heta}JA}$	833	°C/W		
Operating and Storage Temperature Range		T <sub>j</sub> , T <sub>STG</sub>	-55 to +150	°C		

# Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

				-			<b>T</b> ( <b>O</b> 114)
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage (Note 3)			-50	—	_	V	$I_{C} = 10 \mu A, I_{B} = 0$
Collector-Emitter Breakdown Voltage (Note 3)			-45	—		V	$I_{\rm C} = 10 {\rm mA}, \ I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	(Note 3)	V <sub>(BR)CEO</sub> V <sub>(BR)EBO</sub>	-5	—	_	V	$I_{E} = 1 \mu A, I_{C} = 0$
DC Current Gain (Note 3)	Current Gain A B C	h <sub>FE</sub>	125 220 420	 290 520	250 475 800	_	$V_{CE}$ = -5.0V, $I_C$ = -2.0mA
Collector-Emitter Saturation Voltage	(Note 3)	V <sub>CE(SAT)</sub>			-300 -650	mV	$I_{C} = -10mA$ , $I_{B} = -0.5mA$ $I_{C} = -100mA$ , $I_{B} = -5.0mA$
Base-Emitter Saturation Voltage (Note 3)				-700 -900		mV	$I_{C} = -10mA$ , $I_{B} = -0.5mA$ $I_{C} = -100mA$ , $I_{B} = -5.0mA$
Base-Emitter Voltage (N		V <sub>BE(ON)</sub>	-600	—	-750 -820	mV	V <sub>CE</sub> = -5.0V, I <sub>C</sub> = -2.0mA V <sub>CE</sub> = -5.0V, I <sub>C</sub> = -10mA
Collector-Cutoff Current	(Note 3)		_	_	-15	NA	$V_{CB} = -30V$
		ICBO		—	-4.0	μA	V <sub>CB</sub> = -30V, T <sub>A</sub> = 150°C
Gain Bandwidth Product			100	—	_	MHz	V <sub>CE</sub> = -5.0V, I <sub>C</sub> = -10mA, f = 100MHz
Output Capacitance		C <sub>OB</sub>	_	—	4.5	pF	V <sub>CB</sub> = -10V, f = 1.0MHz
Noise Figure		NF	_	_	10	dB	$\label{eq:lc} \begin{array}{l} {\sf I}_{\sf C} = -0.2 \text{mA}, \ {\sf V}_{\sf C{\sf E}} = -5.0 \text{Vdc}, \\ {\sf R}_{\sf S} = 2.0 \text{K}\Omega, \ {\sf f} = 1.0 \text{KHz}, \\ {\sf BW} = 200 \text{Hz} \end{array}$

1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

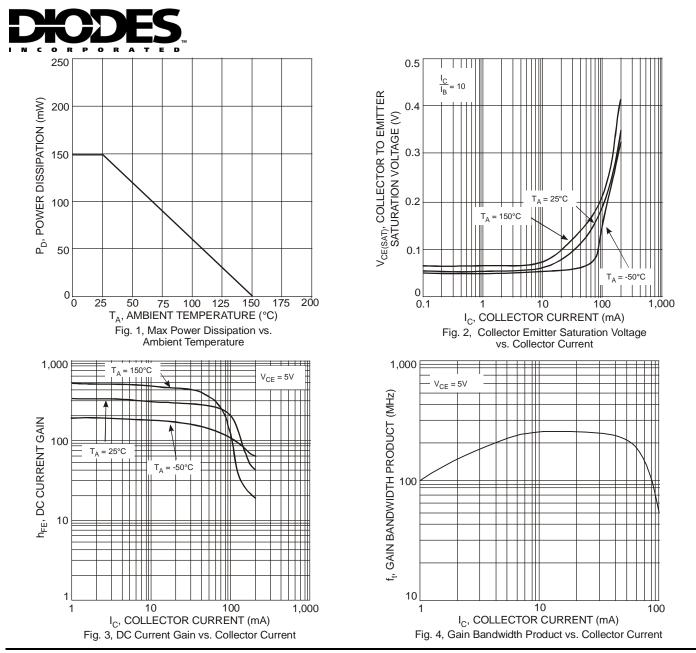
2. No purposefully added lead

3. Short duration pulse test used to minimize self-heating effect.

4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.

5. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

Notes:



### Ordering Information (Note 6)

Device	Packaging	Shipping
BC857AT-7-F	SOT-523	3000/Tape & Reel
BC857BT-7-F	SOT-523	3000/Tape & Reel
BC857CT-7-F	SOT-523	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## **Marking Information**

XXYM	
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XX = Product Type Marking Code (See Page 1), e.g. 3V = BC857AT YM = Date Code Marking Y = Year (ex: N = 2002)

M = Month (ex: 9 = September)

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	К	L	М	Ν	Р	R	S	Т	U	V	W	Х	Y	Z
Month	Jan	Fe	b I	Mar	Apr	Мау	Ju	n	Jul	Aug	Sep	Oc	t l	lov	Dec
Code	1	2		3	4	5	6		7	8	9	0		Ν	D

DS30275 Rev. 9 - 2



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